



DGD05463

HIGH-FREQUENCY HALF-BRIDGE GATE DRIVER WITH PROGRAMMABLE DEADTIME

Description

The DGD05463 is a high-frequency half-bridge gate driver capable of driving n-channel MOSFETs in a half-bridge configuration. The floating high-side driver is rated up to 50V.

The DGD05463 logic inputs are compatible with standard TTL and CMOS levels (down to 3.3V) to interface easily with MCUs. UVLO for high-side and low-side will protect a MOSFET with loss of supply. To protect MOSFETs, cross conduction prevention logic prevents the HO and LO outputs from being on at the same time.

Fast and well-matched propagation delays allow a higher switching frequency, which enable a smaller, more compact power switching design using smaller associated components. The DGD05463 is offered in the W-DFN3030-10 (Type TH) and MSOP-10 packages and operates over an extended -40°C to +125°C temperature range.

Features

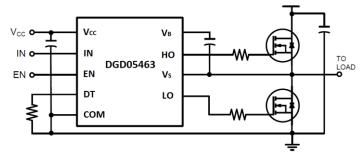
- 50V Floating High-Side Driver
- Drives Two N-Channel MOSFETs in a Half-Bridge Configuration
- 1.5A Source / 2.5A Sink Output Current Capability
- Internal Bootstrap Diode Included
- Undervoltage Lockout for High-Side and Low-Side Drivers
- Programmable Deadtime to Protect MOSFETs
- Logic Input (IN and EN) 3.3V Capability
- Ultra-Low Standby Currents (< 1µA)
- Extended Temperature Range: -40°C to +125°C
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/quality/product-definitions/

Applications

- DC-DC converters
- Motor controls
- · Battery-powered hand tools
- eCig devices
- Class-D power amplifiers

Mechanical Data

- Package: W-DFN3030-10, MSOP-10
- Package Material: Molded Plastic. "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 3 per J-STD-020
- Terminals: Finish Matte Tin Finish.
 Solderable per MIL-STD-202, Method 208 (€3)
- Weight:
 - W-DFN3030-10 (Type TH): 0.017 grams (Approximate)
 - MSOP-10: 0.0286 grams (Approximate)



Typical Configuration

W-DFN3030-10 (Type TH)



A TOP

Top View Bottom View

MSOP-10



Top View

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.



Ordering Information (Note 4)

Part Number	Package	Marking	Reel Size (inches)	Tape Width (mm)	Packing	
Fait Number	Fackage	Warking	Reel Size (Illulies)	rape widin (ililii)	Qty.	Carrier
DGD05463FN-7	W-DFN3030-10 (Type TH)	DGD05463	7	8	3000	Reel
DGD05463M10-13	MSOP-10	DGD05463	13	12	2500	Reel

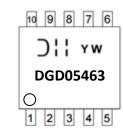
Note:

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

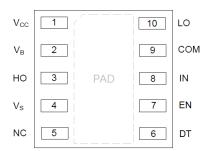


DGD05463 = Product Type Marking Code YY = Year (ex: 24 = 2024) WW = Week (01 to 53)

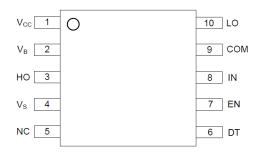


DII = Manufacturer's Code Marking
DGD05463 = Product Type Marking Code
Y = Year: 0 to 9 (ex: 4 = 2024)
W = Week: A to Z : week 1 to 26
a to z : week 27 to 52

Pin Diagrams



Top View: W-DFN3030-10 (Type TH)



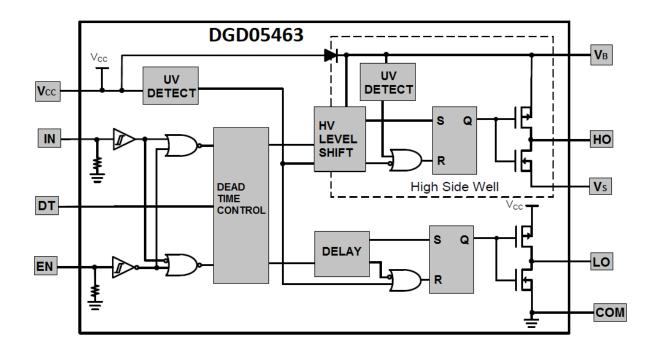
Top View: MSOP-10

Pin Descriptions

Pin Number	Pin Name	Function
1	Vcc	Low-Side and Logic Supply
2	V _B	High-Side Floating Supply
3	НО	High-Side Gate Drive Output
4	Vs	High-Side Floating Supply Return
5	NC	No Connection (No Internal Connection)
6	DT	Deadtime Control
7	EN	Logic Input Enable, a Logic Low Turns Off Gate Driver
8	IN	Logic Input for High-Side and Low-Side Gate Driver Outputs (HO and LO), in Phase with HO
9	COM	Low-Side and Logic Return
10	LO	Low-Side Gate Drive Output
PAD	Substrate	Connect to COM on PCB (For W-DFN3030-10 (Type TH) Only)



Functional Block Diagram





Absolute Maximum Ratings (@ TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
High-Side Floating Positive Supply Voltage	VB	-0.3 to +60	V
High-Side Floating Negative Supply Voltage	Vs	V _B -14 to V _B +0.3	V
High-Side Floating Output Voltage	Vно	Vs-0.3 to V _B +0.3	V
Offset Supply Voltage Transient	dVs/dt	50	V/ns
Logic and Low-Side Fixed Supply Voltage	Vcc	-0.3 to +14	V
Low-Side Output Voltage	V _{LO}	-0.3 to V _{CC} +0.3	V
Logic Input Voltage (IN and EN)	Vin	-0.3 to Vcc+0.3	V

Thermal Characteristics – W-DFN3030-10 (Type TH) (@ TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation Linear Derating Factor (Note 5)	Po	0.4	W
Thermal Resistance, Junction to Ambient (Note 5)	R _{0JA}	64	°C/W
Thermal Resistance, Junction to Case (Note 5)	Rejc	42	°C/W
Operating Temperature	TJ	+150	
Lead Temperature (Soldering, 10s)	TL	+300	°C
Storage Temperature Range	Tstg	-55 to +150	

5. When mounted on a standard JEDEC 2-layer FR-4 board. Note:

Thermal Characteristics – MSOP-10 (@ TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation Linear Derating Factor (Note 6)	PD	0.75	W
Thermal Resistance, Junction to Ambient (Note 6)	Reja	166	°C/W
Thermal Resistance, Junction to Case (Note 6)	Rejc	32	°C/W
Operating Temperature	TJ	+150	
Lead Temperature (Soldering, 10s)	T∟	+300	°C
Storage Temperature Range	Tstg	-55 to +150	

Note: 6. When mounted on a standard JEDEC 2-layer FR-4 board with minimum recommended pad layout.

Recommended Operating Conditions

Parameter	Symbol	Min	Max	Unit
High-Side Floating Supply	V _B	V _S + 4.2	V _S + 14	V
High-Side Floating Supply Offset Voltage	Vs	(Note 7)	50 (Note 8)	V
High-Side Floating Output Voltage	Vно	Vs	VB	V
Logic and Low-Side Fixed Supply Voltage	Vcc	4.5 (Note 9)	14	V
Low-Side Output Voltage	VLO	0	Vcc	V
Logic Input Voltage (IN and EN)	Vin	0	5	V
Ambient Temperature	TA	-40	+125	°C

Notes:

- 7. Logic operation for $V_{\mbox{\scriptsize S}}$ of -5V to +50V.
- 8. Provided V_B does not exceed absolute maximum rating of 60V.
- 9. For operation of $V_{CC} = 4.5V$ to 4.9V, an external bootstrap Schottky diode (0.3V V_{FD} , 1A) is necessary, as shown in Figure 3. For operation $V_{CC} \ge 4.9V$, the external Schottky diode is not required.



DC Electrical Characteristics (V_{CC} = V_{BS} = 12V, COM = V_S = 0V, @ T_A = +25°C, unless otherwise specified.) (Note 10)

Parameter	Symbol	Min	Тур	Max	Unit	Condition
Logic "1" Input Voltage	ViH	2.4	_	_	V	_
Logic "0" Input Voltage	VIL	_	_	0.8	V	_
Enable Logic "1" Input Voltage	VENIH	1.5	_	_	V	_
Enable Logic "0" Input Voltage	VENIL	_	_	0.7	V	_
Input Voltage Hysteresis	VINHYS	_	0.6	_	V	_
High-Level Output Voltage, V _{BIAS} - V _O	VoH	_	0.45	0.6	V	I _{O+} = 100mA
Low-Level Output Voltage, Vo	Vol	_	0.15	0.22	V	Io- = 100mA
Offset Supply Leakage Current	ILK	_	10	50	μΑ	V _B = V _S = 60V
V _{CC} Shutdown Supply Current	Iccsd	_	0	1	μΑ	$V_{IN} = 0V$ or $5V$, $V_{EN} = 0V$
Vcc Quiescent Supply Current	Iccq	_	0.28	0.5	mA	$V_{IN} = 0V \text{ or } 5V$ $R_{DT} = 100k\Omega$
Vcc Operating Supply Current	Іссор	_	7.6	_	mA	fs = 500kHz, C _L = 1000pF
V _{BS} Quiescent Supply Current	IBSQ	_	32	100	μΑ	VIN = 0V or 5V
V _{BS} Operating Supply Current	I _{BSOP}	_	7.6	_	mA	$fs = 500kHz, C_L = 1000pF$
Logic "1" Input Bias Current	I _{IN+}	_	25	60	μΑ	Vin = 5V
Logic "0" Input Bias Current	IIN-	_	0	1	μΑ	VIN = 0V
V _{BS} Supply Undervoltage Positive Going Threshold	V _{BSUV+}	3.3	3.8	4.4	V	_
V _{BS} Supply Undervoltage Negative Going Threshold	V _{BSUV} -	2.9	3.3	3.9	V	_
Vcc Supply Undervoltage Positive Going Threshold	Vccuv+	3.3	3.8	4.4	V	_
Vcc Supply Undervoltage Negative Going Threshold	Vccuv-	2.9	3.3	3.9	V	_
Output High Short-Circuit Pulsed Current	lo+	1.0	1.5	_	Α	Vo = 0V, Pw ≤ 10µs
Output Low Short-Circuit Pulsed Current	lo-	1.9	2.5	_	Α	Vo = 15V, Pw ≤ 10µs
Forward Voltage of Bootstrap Diode	V _{F1}	_	0.67	_	V	I _F = 100μA
Forward Voltage of Bootstrap Diode	V _{F2}	_	1.7	_	V	IF = 100mA

Note:

AC Electrical Characteristics (V_{CC} = V_{BS} = 12V, COM = V_S = 0V, C_L = 1000pF, @T_A = +25°C, unless otherwise specified.)

Parameter	Symbol	Min	Тур	Max	Unit	Condition
Turn on Branagation Daloy, HO 9 LO		65	96	125	ns	$R_{DT} = 10k\Omega$
Turn-on Propagation Delay, HO & LO	ton	350	463	580	ns	$R_{DT} = 100k\Omega$
Turn-off Propagation Delay, HO & LO	t _{off}	_	22	56	ns	_
Turn-on Rise Time	tr	_	17	35	ns	_
Turn-off Fall Time	tf	_	12	25	ns	_
Delay Matching	t _{DM}	_	_	50	ns	_
Doodking or to a confidence of the confidence of	4	40	70	100	ns	$R_{DT} = 10k\Omega$
Deadtime: tot lo-но & tot но-lo	tor	300	430	560	ns	$R_{DT} = 100k\Omega$
Deadtime Matching	t _{MDT}	_	_	50	ns	$R_{DT} = 100k\Omega$

^{10.} The V_{IN} and I_{IN} parameters are applicable to the two logic pins: IN and EN. The V_O and I_O parameters are applicable to the respective output pins: HO and LO.



Timing Waveforms

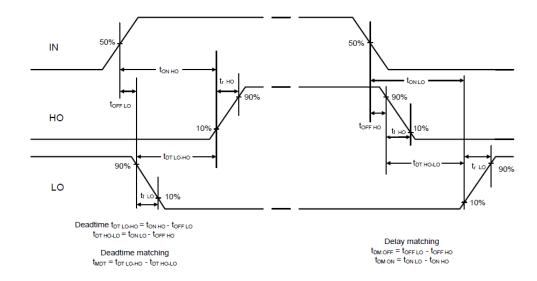


Figure 1. Switching Time Waveform Definitions

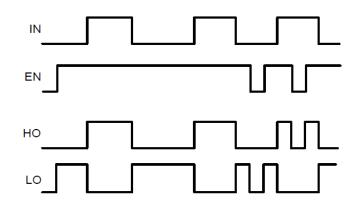


Figure 2. Input / Output Timing Diagram

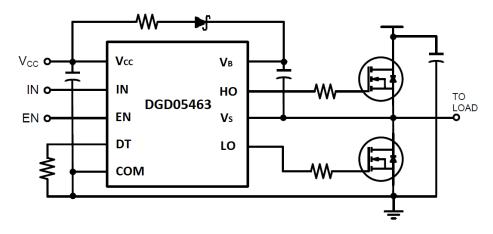


Figure 3. Typical application necessary for $V_{CC} = 4.5 \text{V}$ to 4.9V operation. For $V_{CC} \ge 4.9 \text{V}$, the bootstrap Schottky diode (0.3V Voltage drop, 1A) and resistor are not required.



Typical Performance Characteristics (V_{CC} = 12V, @ T_A = +25°C, unless otherwise specified.)

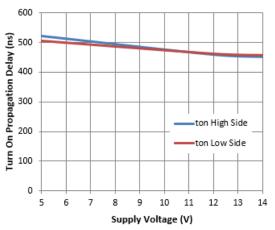


Figure 4. Turn-on Propagation Delay vs. Supply Voltage

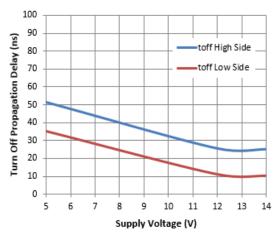


Figure 6. Turn-off Propagation Delay vs. Supply Voltage

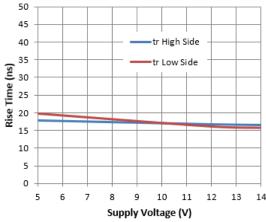


Figure 8. Rise Time vs. Supply Voltage

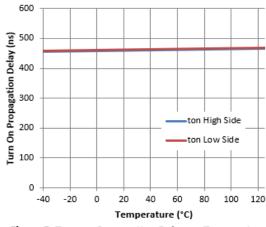


Figure 5. Turn-on Propagation Delay vs. Temperature

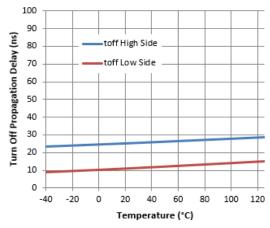


Figure 7. Turn-off Propagation Delay vs. Temperature

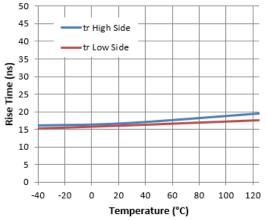


Figure 9. Rise Time vs. Temperature



Typical Performance Characteristics (V_{CC} = 12V, @ T_A = +25°C, unless otherwise specified.) (continued)

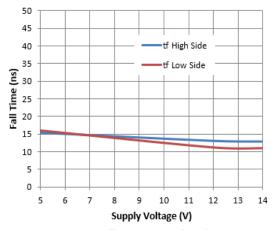


Figure 10. Fall Time vs. Supply Voltage

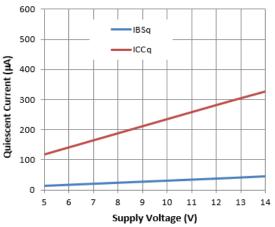


Figure 12. Quiescent Current vs. Supply Voltage

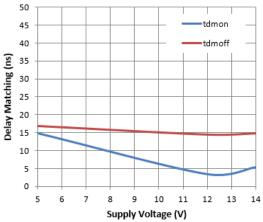


Figure 14. Delay Matching vs. Supply Voltage

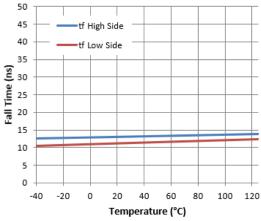


Figure 11. Fall Time vs. Temperature

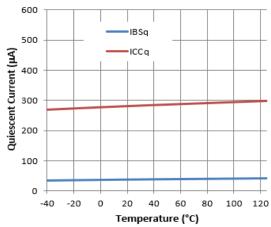


Figure 13. Quiescent Current vs. Temperature

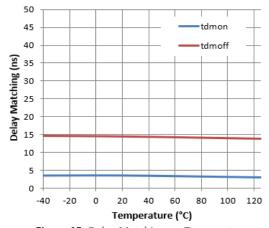


Figure 15. Delay Matching vs. Temperature



Typical Performance Characteristics (V_{CC} = 12V, @ T_A = +25°C, unless otherwise specified.) (continued)

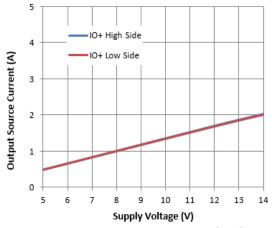


Figure 16. Output Source Current vs. Supply Voltage

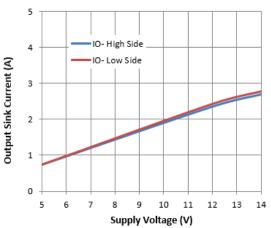


Figure 18. Output Sink Current vs. Supply Voltage

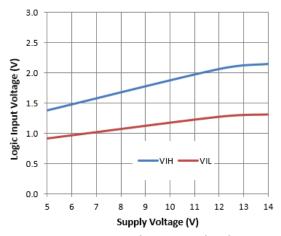


Figure 20. Logic Input Voltage vs. Supply Voltage

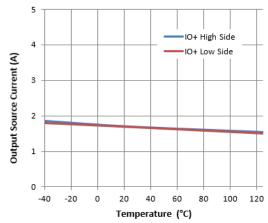


Figure 17. Output Source Current vs. Temperature

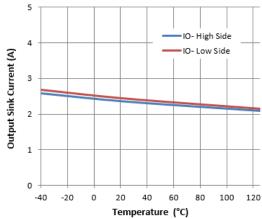


Figure 19. Output Sink Current vs. Temperature

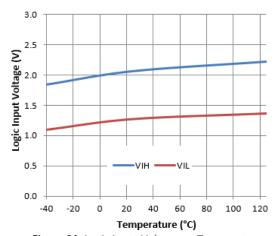


Figure 21. Logic Input Voltage vs. Temperature



$\textbf{Typical Performance Characteristics} \ (V_{CC} = 12V, \ @ \ T_A = +25^{\circ}C, \ unless \ otherwise \ specified.) \ (continued)$

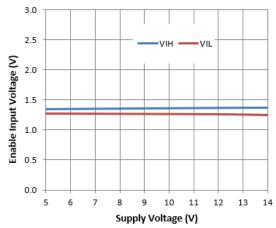


Figure 22. Enable Input Voltage vs. Supply Voltage

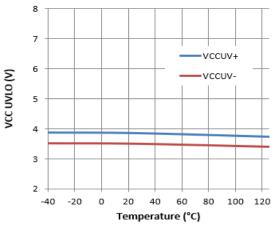


Figure 24. VCC UVLO vs. Temperature

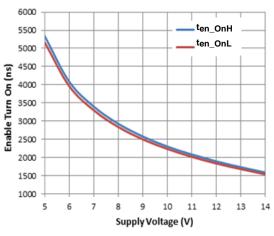


Figure 26. EN to Output ton vs. Supply Voltage

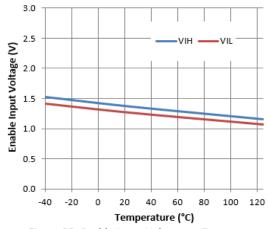


Figure 23. Enable Input Voltage vs. Temperature

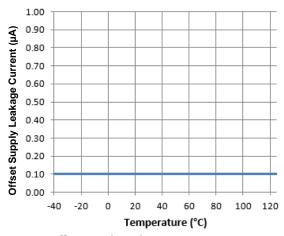


Figure 25. Offset Supply Leakage Current vs. Temperature

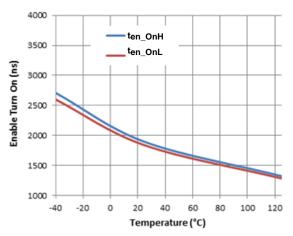


Figure 27. EN to Output ton vs. Temperature



$\textbf{Typical Performance Characteristics} \ (V_{CC} = 12V, @ T_A = +25^{\circ}C, \text{ unless otherwise specified.}) \ (\text{continued})$

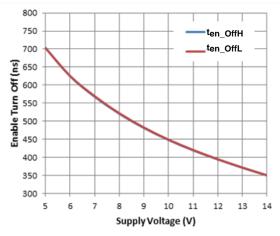


Figure 28. EN to Output toff vs. Supply Voltage

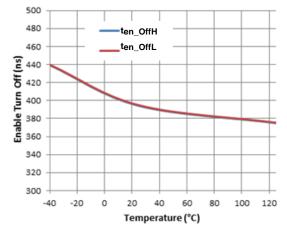


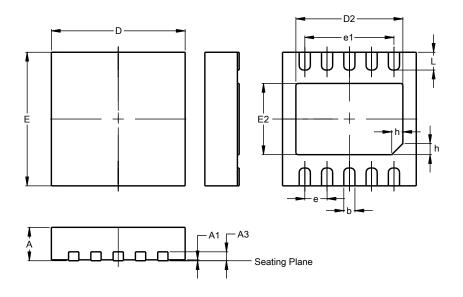
Figure 29. EN to Output toff vs. Temperature



Package Outline Dimensions

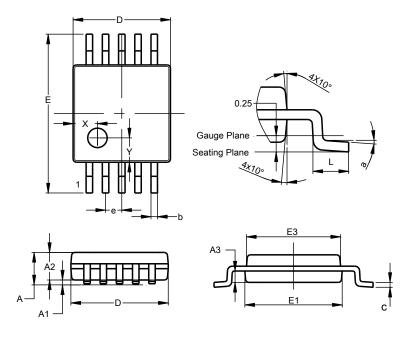
Please see http://www.diodes.com/package-outlines.html for the latest version.

W-DFN3030-10 (Type TH)



	W-DFN3030-10					
	(Type TH)					
Dim	Min	Max	Тур			
Α	0.70	0.80	0.75			
A1	-	0.05	0.02			
А3	0.18	0.25	0.20			
b	0.18	0.30	0.25			
D	2.90	3.10	3.00			
D2	2.40	2.60	2.50			
е		0.50BS	SC SC			
e1		2.00BS	SC SC			
Е	2.90	3.10	3.00			
E2	1.45	1.65	1.55			
h	0.20	0.30	0.25			
L	0.30	0.50	0.40			
All	Dimen	sions i	n mm			

MSOP-10



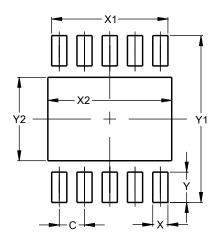
MSOP-10				
Dim	Min	Max	Тур	
Α	-	1.10	-	
A1	0.05	0.15	0.10	
A2	0.75	0.95	0.86	
A3	0.29	0.49	0.39	
b	0.17	0.27	0.20	
С	0.08	0.23	0.15	
ם	2.95	3.05	3.00	
е	-	-	0.50	
Е	4.80	5.00	4.90	
E1	2.95	3.05	3.00	
E3	2.85	3.05	2.95	
L	0.40	0.80	0.60	
Х			0.750	
Υ			0.750	
а	0°	8°	4°	
All D	imens	sions i	n mm	



Suggested Pad Layout

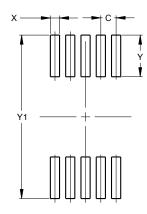
Please see http://www.diodes.com/package-outlines.html for the latest version.

W-DFN3030-10 (Type TH)



Dimensions	Value (in mm)
С	0.500
Х	0.300
X1	2.300
X2	2.600
Y	0.600
Y1	3.300
Y2	1.650

MSOP-10



Dimensions	Value (in mm)
С	0.50
Х	0.30
Y	1.35
Y1	5.30



IMPORTANT NOTICE

- 1. DIODES INCORPORATED (Diodes) AND ITS SUBSIDIARIES MAKE NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO ANY INFORMATION CONTAINED IN THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).
- 2. The Information contained herein is for informational purpose only and is provided only to illustrate the operation of Diodes' products described herein and application examples. Diodes does not assume any liability arising out of the application or use of this document or any product described herein. This document is intended for skilled and technically trained engineering customers and users who design with Diodes' products. Diodes' products may be used to facilitate safety-related applications; however, in all instances customers and users are responsible for (a) selecting the appropriate Diodes products for their applications, (b) evaluating the suitability of Diodes' products for their intended applications, (c) ensuring their applications, which incorporate Diodes' products, comply the applicable legal and regulatory requirements as well as safety and functional-safety related standards, and (d) ensuring they design with appropriate safeguards (including testing, validation, quality control techniques, redundancy, malfunction prevention, and appropriate treatment for aging degradation) to minimize the risks associated with their applications.
- 3. Diodes assumes no liability for any application-related information, support, assistance or feedback that may be provided by Diodes from time to time. Any customer or user of this document or products described herein will assume all risks and liabilities associated with such use, and will hold Diodes and all companies whose products are represented herein or on Diodes' websites, harmless against all damages and liabilities.
- 4. Products described herein may be covered by one or more United States, international or foreign patents and pending patent applications. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks and trademark applications. Diodes does not convey any license under any of its intellectual property rights or the rights of any third parties (including third parties whose products and services may be described in this document or on Diodes' website) under this document.
- provided Diodes' products are subject to Diodes' Standard Terms and Conditions of Sale (https://www.diodes.com/about/company/terms-and-conditions/terms-and-conditions-of-sales/) or other applicable terms. This document does not alter or expand the applicable warranties provided by Diodes. Diodes does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel.
- 6. Diodes' products and technology may not be used for or incorporated into any products or systems whose manufacture, use or sale is prohibited under any applicable laws and regulations. Should customers or users use Diodes' products in contravention of any applicable laws or regulations, or for any unintended or unauthorized application, customers and users will (a) be solely responsible for any damages, losses or penalties arising in connection therewith or as a result thereof, and (b) indemnify and hold Diodes and its representatives and agents harmless against any and all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim relating to any noncompliance with the applicable laws and regulations, as well as any unintended or unauthorized application.
- 7. While efforts have been made to ensure the information contained in this document is accurate, complete and current, it may contain technical inaccuracies, omissions and typographical errors. Diodes does not warrant that information contained in this document is error-free and Diodes is under no obligation to update or otherwise correct this information. Notwithstanding the foregoing, Diodes reserves the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes.
- 8. Any unauthorized copying, modification, distribution, transmission, display or other use of this document (or any portion hereof) is prohibited. Diodes assumes no responsibility for any losses incurred by the customers or users or any third parties arising from any such unauthorized use.
- 9. This Notice may be periodically updated with the most recent version available at https://www.diodes.com/about/company/terms-and-conditions/important-notice

The Diodes logo is a registered trademark of Diodes Incorporated in the United States and other countries. All other trademarks are the property of their respective owners.

© 2024 Diodes Incorporated. All Rights Reserved.

www.diodes.com

DGD05463 14 of 14 February 2024

Document number: DS40512 Rev. 7 - 2 www.diodes.com © 2024 Copyright Diodes Incorporated. All Rights Reserved.